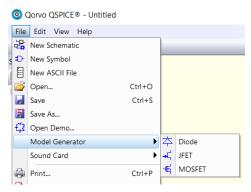
Qspice - Model Generators Guide by KSKelvin

KSKelvin Kelvin Leung

Created on: 10-29-2024 Last Update: 6-29-2025

Model Generator and Precaution in using this Guide

- Model Generator
 - Model generators are in File > Model Generator > Diode/JFET/MOSFET
 - Execute one of these model generators, within the subprogram, it has official HELP



- Precaution in using this Guide
 - The model generator appears to still be subject to change. If you are unable to replicate the example provided in this guideline, it may be related to a change in the model generator
 - I cannot guarantee the accuracy of this guideline as it heavily relies on parameter studies through these model generators. This guideline is still in its preliminary status

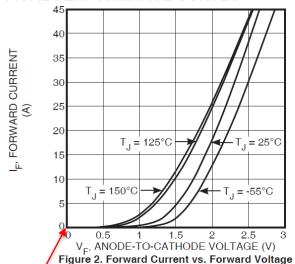


Digitize with Crosshair Cursor and Arrow Slight Adjustment

Step #2 : [Crosshair Cursor]

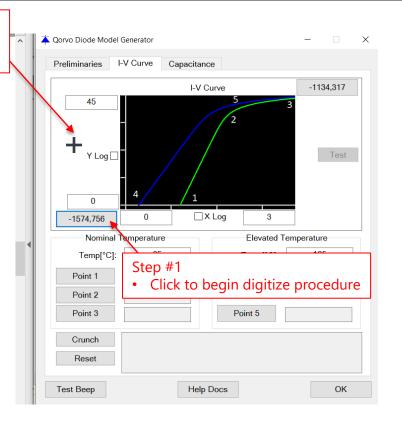
 Move cursor to this area, hold Left mouse button Now, the cursor become a crosshair

TYPICAL PERFORMANCE CURVES

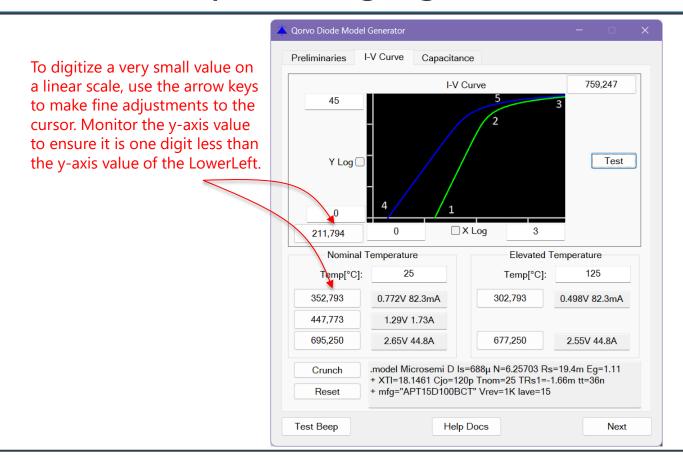


Step #3:

- Move crosshair cursor to pdf to digitize lower left corner (Can use arrow key to adjust crosshair position precisely)
- · Release left mouse button and location is digitized
- [Repeat Step #2 and #3 until all points is digitized]



Useful Technique in using Digitize



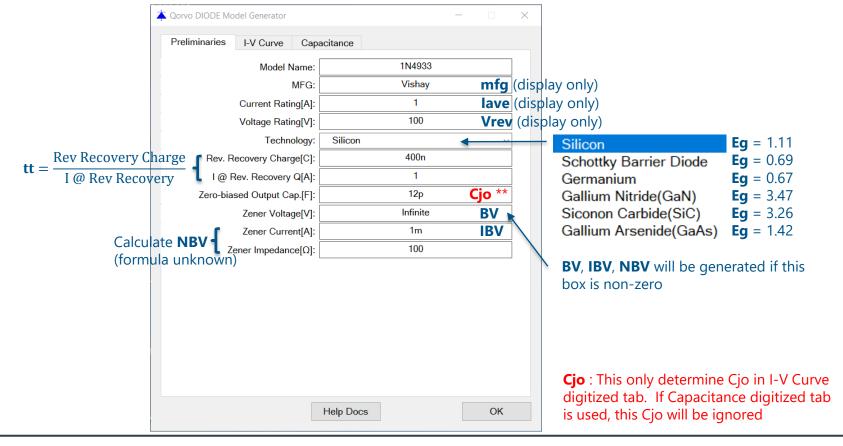
Diode Model Generator DIODE.exe

Diode Model Generator

Parameters Generation

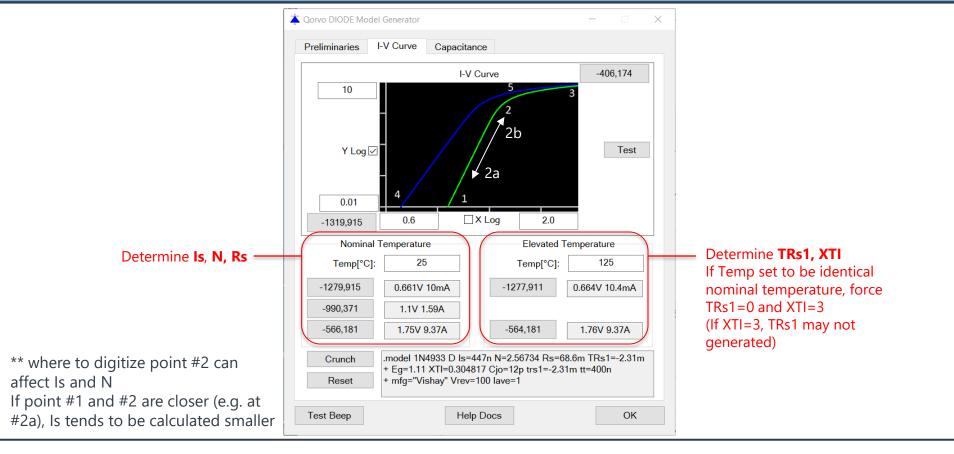
Diode Model Generator – Preliminaries Tab

Determine: mfg, lave, Vrev, Eg, tt, Cjo**, BV, IBV, NBV



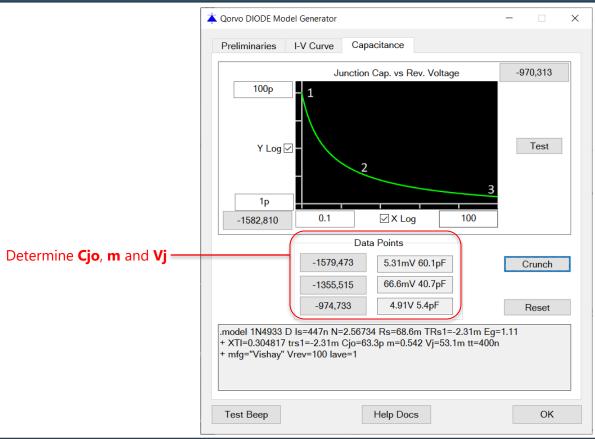
Diode Model Generator – I-V Curve Tab

Determine: Is, N, Rs, TRs1, XTI



Diode Model Generator – Capacitance Tab

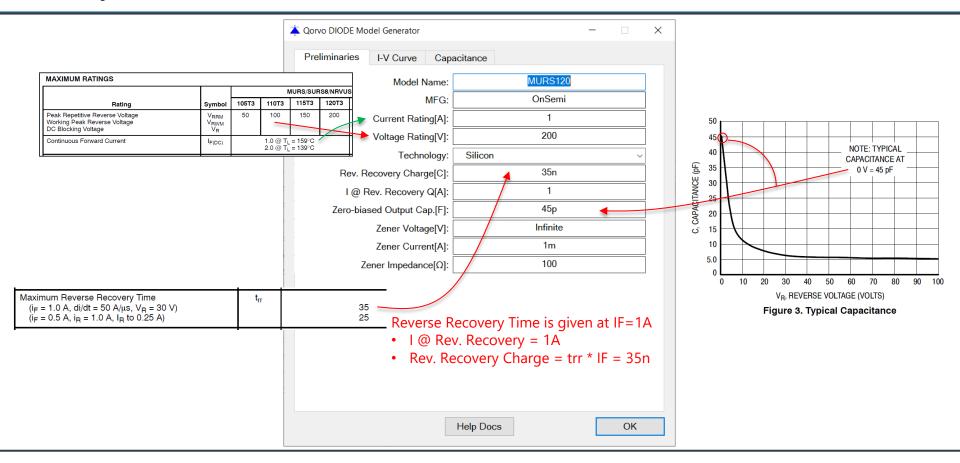
Determine: Cjo, m, Vj



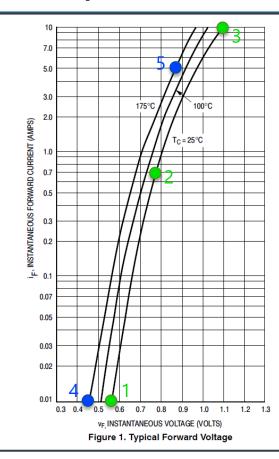
Diode Model Generator

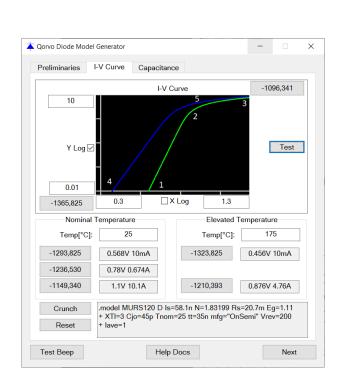
Example – Datasheet of Onsemi MURS1200

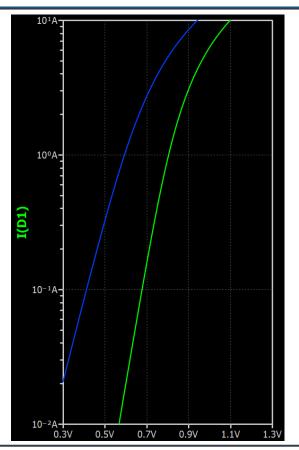
Example – Onsemi MURS120 Datasheet to Model Generator



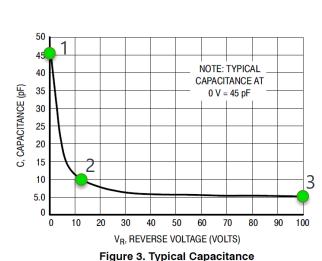
Example – Onsemi MURS120 Datasheet to Model Generator



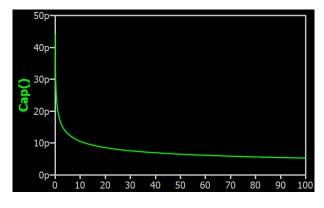




Example – Onsemi MURS120 Datasheet to Model Generator



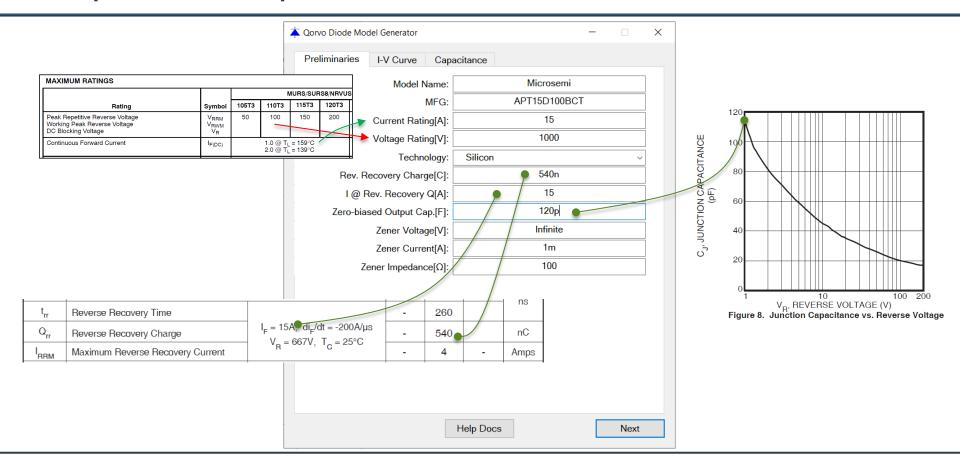
Qorvo Diode Model Generator Capacitance Preliminaries I-V Curve -1064.464 Junction Cap. vs Rev. Voltage 50p Test Y Log -1391,693 X Log 100 Data Points -1391,485 0V 45.4pF Crunch -1350,648 12.5V 9.83pF -1065,669 99.7V 5.24pF Reset .model MURS120 D Is=58.1n N=1.83199 Rs=20.7m Eg=1.11 XTI=3 Cjo=45.4p + m=0.304 Vj=82.1m tt=35n tt=35n mfg="OnSemi" Vrev=200 lave=1 Test Beep Help Docs Done



Diode Model Generator

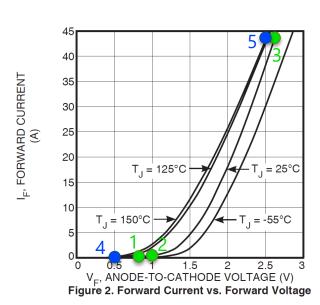
Example – Datasheet of Microchip APT15D100BCT

Example – Microchip APT15D100BCT Datasheet to Model Generator

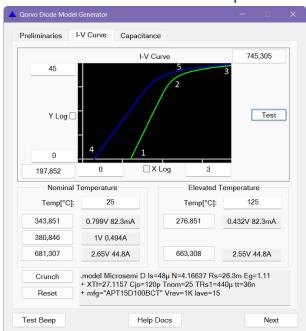


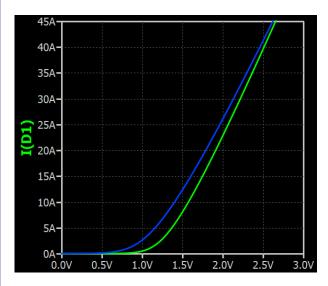
Example – Microchip APT15D100BCT Datasheet to Model Generator

Qspice reference is log plot (y-axis log, x-axis linear), marker 1-5 is different if linear plot is used

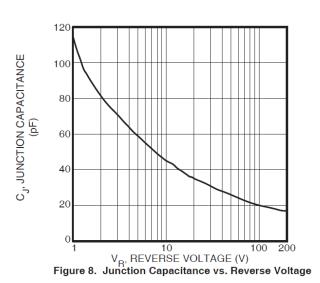


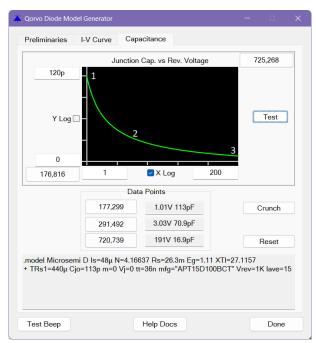
Marker 1 to 5 if linear plot is used (y-axis and x-axis are both linear)

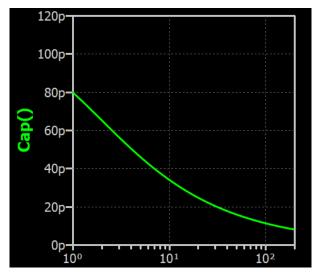




Example – Microchip APT15D100BCT Datasheet to Model Generator







MOSFET Model Generator

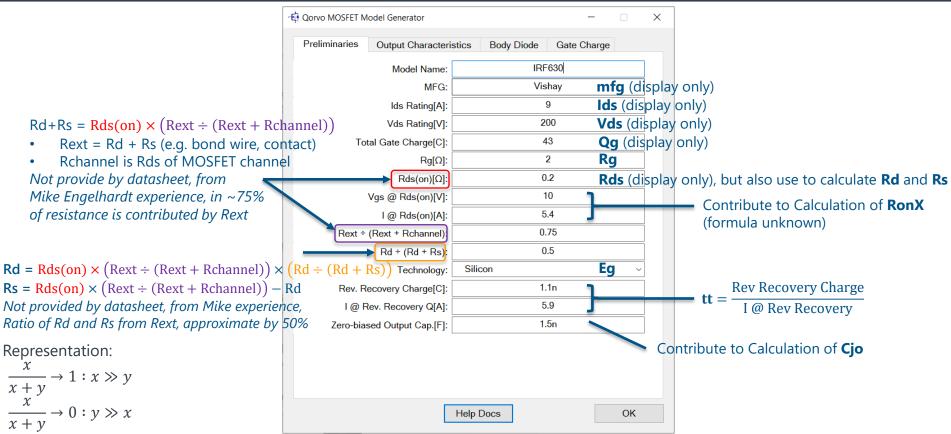
MOSFET.exe

MOSFET Model Generator

Parameters Generation

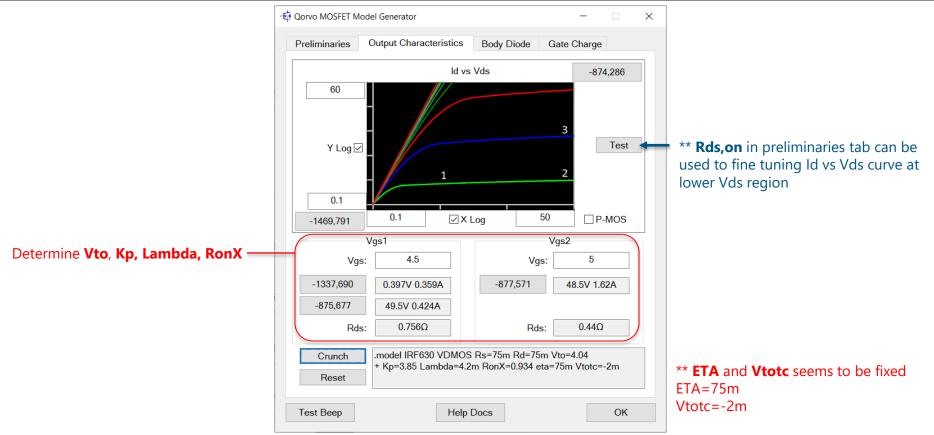
MOSFET Model Generator – Preliminaries Tab

Determine: mfg, Ids, Vds, Qg, Rg, Rds, Rd, Rs, Eg, tt



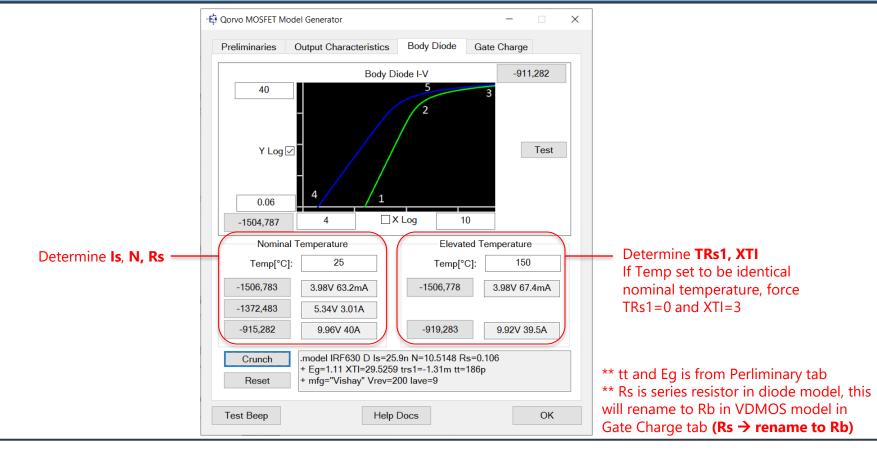
MOSFET Model Generator – Output Characteristics

Determine: Vto, Kp, Lambda, RonX, eta, Vtotc



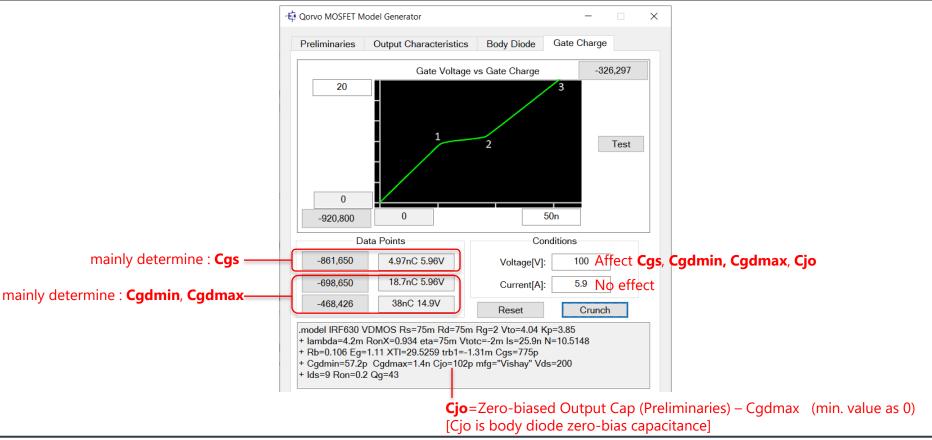
MOSFET Model Generator – Body Diode

Determine: Is, N, Rs, TRs1, XTI



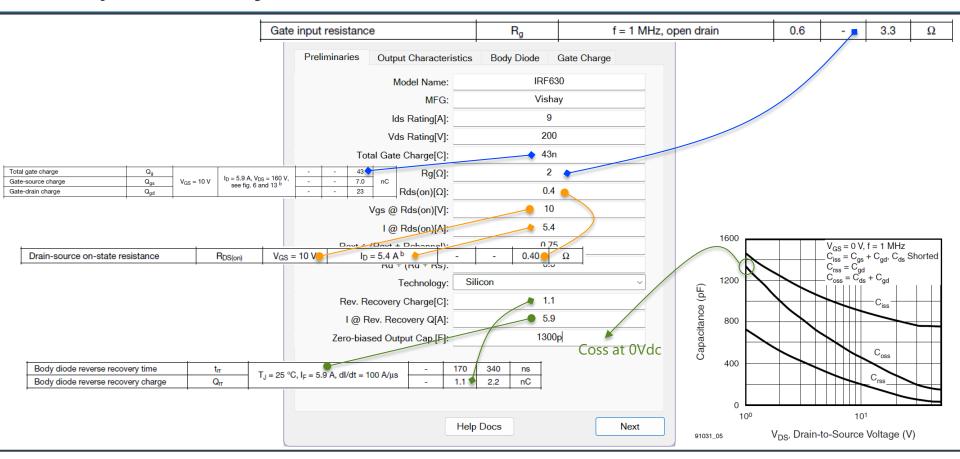
MOSFET Model Generator – Gate Charge

Determine: Cgs, Cgdmin, Cgdmax, Cjo



MOSFET Model Generator

Example – Datasheet of Vishay IRF630



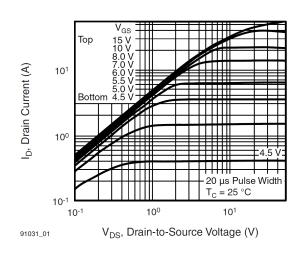
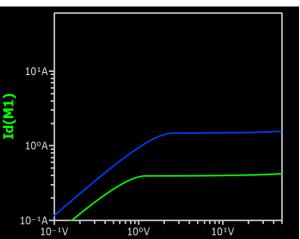


Fig. 1 - Typical Output Characteristics, T_C = 25 °C





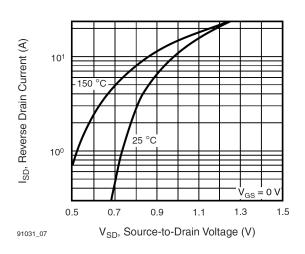
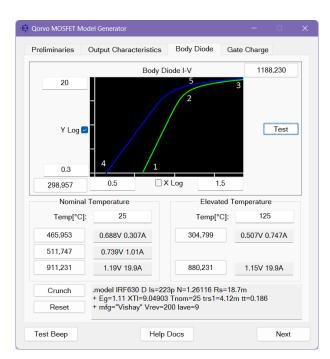
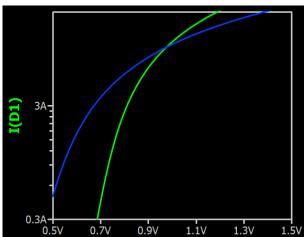


Fig. 7 - Typical Source-Drain Diode Forward Voltage





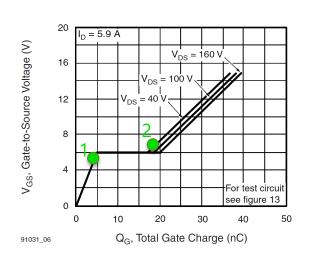
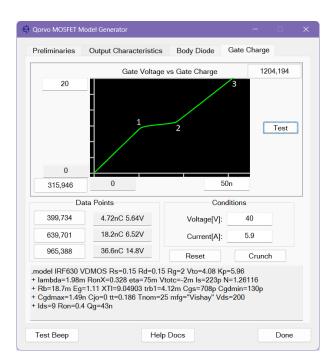
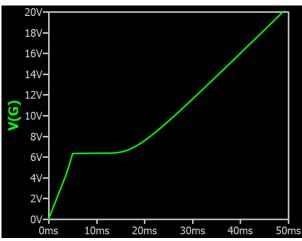


Fig. 6 - Typical Gate Charge vs. Gate-to-Source Voltage

According to Mike, Point #1 and #2 are sampled slightly lower and slightly higher than flat region



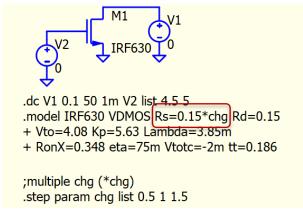


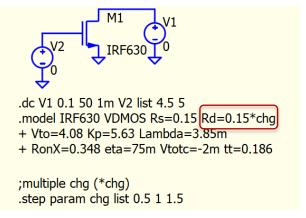
MOSFET Model Generator

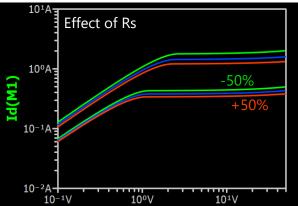
Effect of Model Parameters

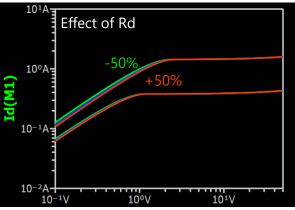
Output Characteristic (Rs, Rd)

Qspice: Sensitivity Study - Output Characteristic.qsch



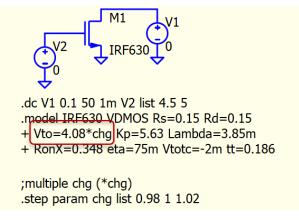


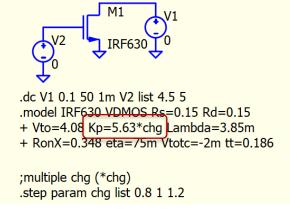


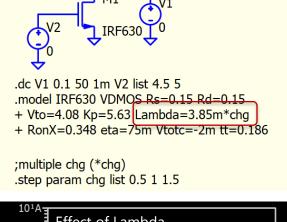


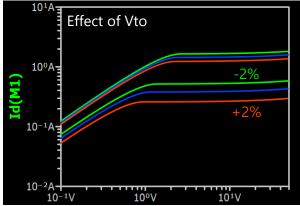
Output Characteristic (Vto, Kp, Lambda)

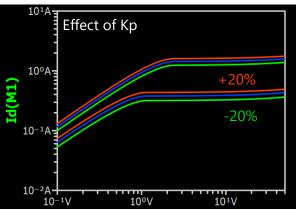
Qspice: Sensitivity Study - Output Characteristic.qsch

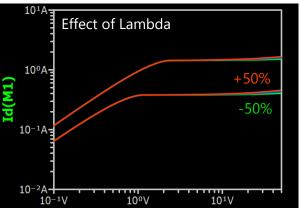










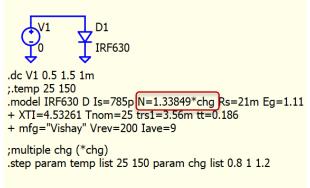


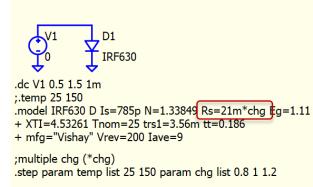
Bode Diode (Is, N, Rs)

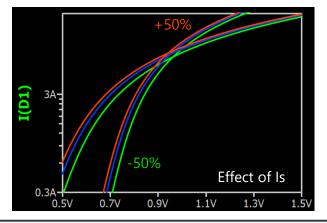
Qspice : Sensitivity Study - Body Diode.qsch

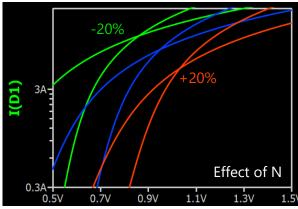
```
U1 IRF630

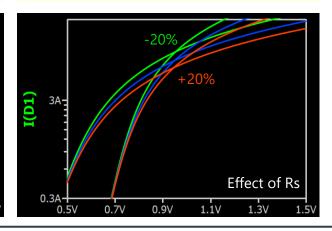
.dc V1 0.5 1.5 1m
;.temp 25 150
.model IRF630 D Is=785p*chg N=1.33849 Rs=21m Eg=1.11
+ XTI=4.53261 Tnom=25 trs1=3.56m tt=0.186
+ mfg="Vishay" Vrev=200 Iave=9
;multiple chg (*chg)
.step param temp list 25 150 param chg list 0.5 1 1.5
```







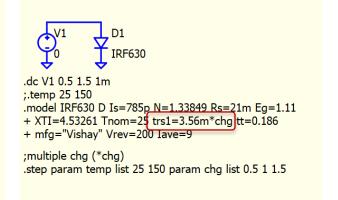


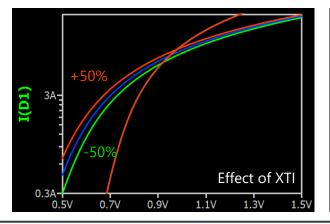


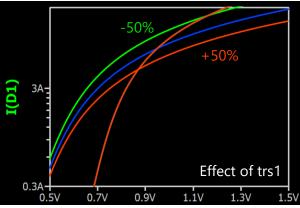
Bode Diode (XTI, trs1): Temperature Effect

Qspice: Sensitivity Study - Body Diode.qsch

```
.dc V1 0.5 1.5 1m
;temp 25 150
.model IRF630 D Is=785p N=1.33849 Rs=21m Eg=1.11
+XTI=4.53261*chg Tnom=25 trs1=3.56m tt=0.186
+ mfg="Vishay" Vrev=200 Iave=9
;multiple chg (*chg)
.step param temp list 25 150 param chg list 0.5 1 1.5
```

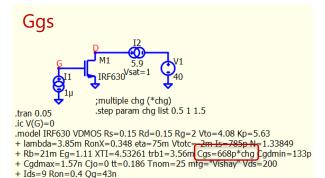


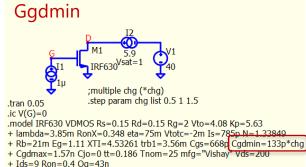


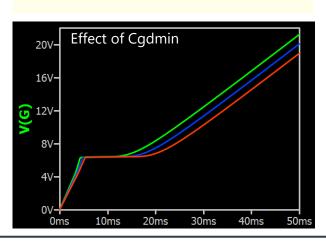


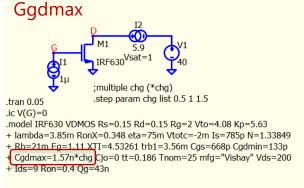
Gate Charge (Cgs, Cgdmin, Cgdmax)

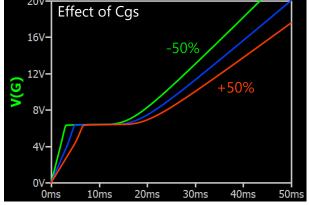
Qspice: Sensitivity Study - Gate Charge.qsch

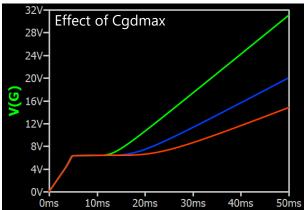






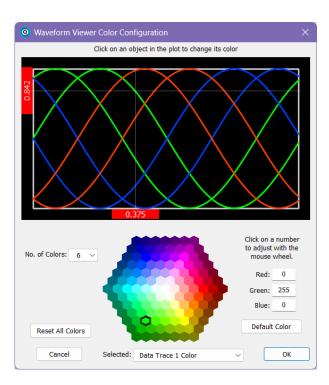






Waveform Viewer Color Configuration for Sensitivity Study

- In sensitivity study, as triple sweep is used in Output Characteristic and Body Diode, color trace in waveform viewer is setup as
 - Data Trace 1 Color: [0,255,0]
 - Data Trace 2 Color: [0,255,0]
 - Data Trace 3 Color : [0,63,255]
 - Data Trace 4 Color: [0,63,255]
 - Data Trace 5 Color: [255,63,0]
 - Data Trace 6 Color: [255,63,0]



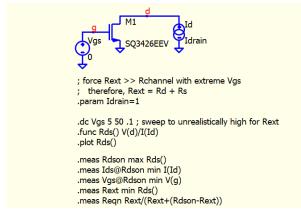
MOSFET Model Generator

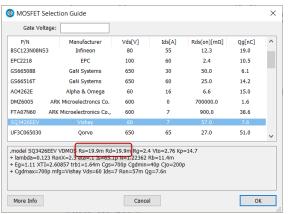
Example – Recreate from a model

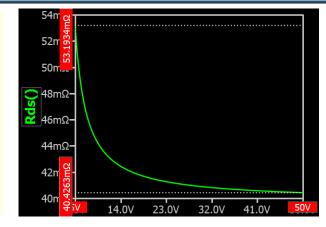
Determine Rds(on), Vgs, Idrain @ Rds(on) and Rext÷(Rext+Rchannel)

Qspice: Preliminaries (Rdson Vgs Idrain and Rext).qsch

- Rext : Rd + Rs
 - Rds(on) is basically consist of Rext (external resistance : Rd, Rs) and Rchannel (channel resistance)
 - To estimate Rext, fully turn ON a FET model with extreme gatesource voltage, which minimized Rchannel and Rds(on) is dominated by Rext
 - In this example, Rs+Rd=Rext=39.8mΩ. And by extreme gatesource, Rext=40.6mΩ







- Now put,
 - Rds(on) = 53.2m Ω
 - Vgs @ Rds(on) = 5V
 - Idrain @ Rds(on) = 1A
 - Rext = Rs+Rd = 40.6m Ω
 - Rchannel@Rds(on) = Rds(on) – Rext = $53.2m\Omega - 40.6m\Omega$ = $12.6m\Omega$
 - Rext÷(Rext+Rchannel) = 40.6Ω /(40.6Ω +12.6 Ω) = 0.763Ω

Determine Rg from a MOSFET Model

Qspice: Preliminaries - Rg.qsch

- Rg
 - Rg is series resistance in gate
 - Rg can be identified with ac analysis and only read the real part with Cartesian representation
 - Now, put
 - Rg = value of Zr()

